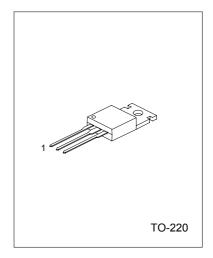
NPN EXPITAXIAL PLANAR **TRANSISTOR**

DESCRIPTION

The UTC BU407 is a NPN expitaxial planar transistor, designed for use in TV Horizontal output and switching applications.

FEATURE

*High breakdown voltage



1:BASE 2:COLLECTOR 3:EMITTER

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Collector Base Voltage	Vсво	330	V
Collector to Emitter Voltage	VCEO	150	V
Emitter To Base Voltage	VEBO	6	V
Collector Current	Ic	7	Α
Base Current	lB	4	Α
Collector Dissipation (Ta=25°C)	Pc	60	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-50 ~ +150	°C

ELECTRICAL CHARACTERISTICS (Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Emitter Sustaining Voltage	BVCEO	IC=100mA, IB=0	150			V
Collect Cutoff Current	ICES	VCE=400V			5	mA
Emitter Cutoff Current	IEBO	VBE=6V, Ic=0			1	mA
Collector-Emitter Saturation Voltage	Vce(sat)	IC=5A, IB=0.5A			1	V
Base-Emitter On Voltage	VBE(sat)	IC=5A, IB=0.5A			1.2	V
DC Current Gain	HFE1	IC=500mA, VCE=5V	25			
	HFE2	IC=2A, VCE=5V	35		200	
	HFE3	IC=5A, VCE=5V	10			
Current Gain Bandwidth Product	fT	Ic=500mA, V _{CE} =10V	10			MHz
		f=1MHz				

CLASSIFICATION OF hFE2

RANK	В	С	D				
RANGE	35-85	75-125	115-200				

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